

FEATURES

- Broadband 1 to 2000MHz
- Low Power (500mW)
- 3 Diff Outputs
- 6 Single Outputs
- High Linearity
- IIP3 = +20dBm
- IIP2 = +50dBm
- NF = 8dB
- >40dB AGC Range
- Ultra Fast AGC
- Gain Tracking Error <1dB

APPLICATIONS

- RF Signal Switching
- RF Signal Level Control
- Phased Arrays
- Instrumentation
- ATE
- Base Station RX and TX
- Adaptive Antenna's Systems
- Video Recorders
- RF Signal Distribution
- Multiple Tuners
- Satellite, Cable, Terrestrial Digital TV Multiple Tuners

Ordering Information

PS12000C1M1A5 (trays)	28 MLP
PS12000C1M1AT (tape & reel)	28 MLP
-40°C to +80°C	

Equivalent Part: ZL40000

Description

The PS12000 is an ultra high linearity RF power divider, with a 75 Ohm Input impedance to a broad band RF input signal.

The signal is buffered through an ultra high linearity 6dB Gain buffer. This is followed by a power divider which splits the buffered signal into 3 signals. One signal is passed through a 200Ohm differential output driver. The other two signals are passed through two separate 0 to -40dB AGC stages before output as two isolated independent differential signals.

The device is built on Plessey Semiconductors' 20GHz Complimentary Bipolar Process.

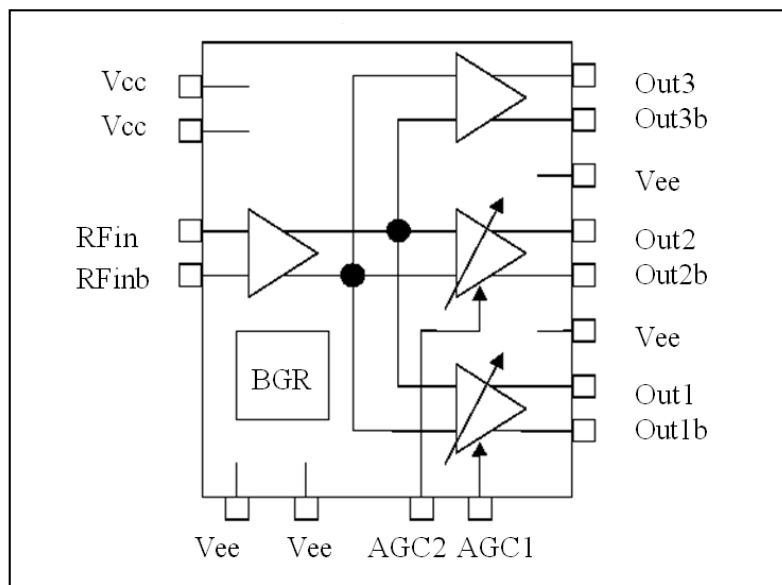


Figure 1 – Functional Block Diagram

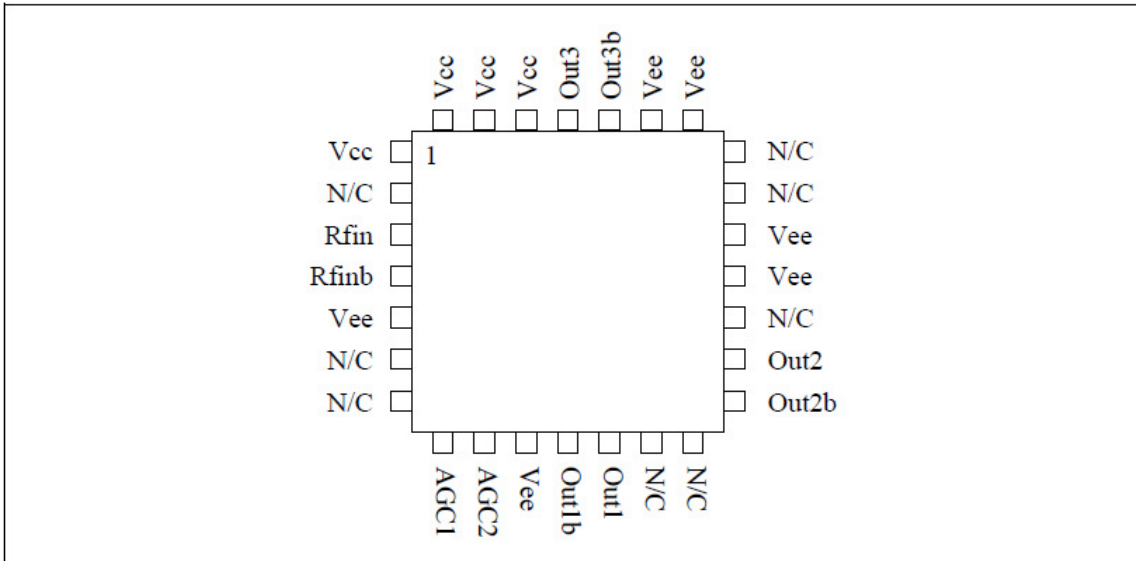


Figure 2 - Pin Diagram

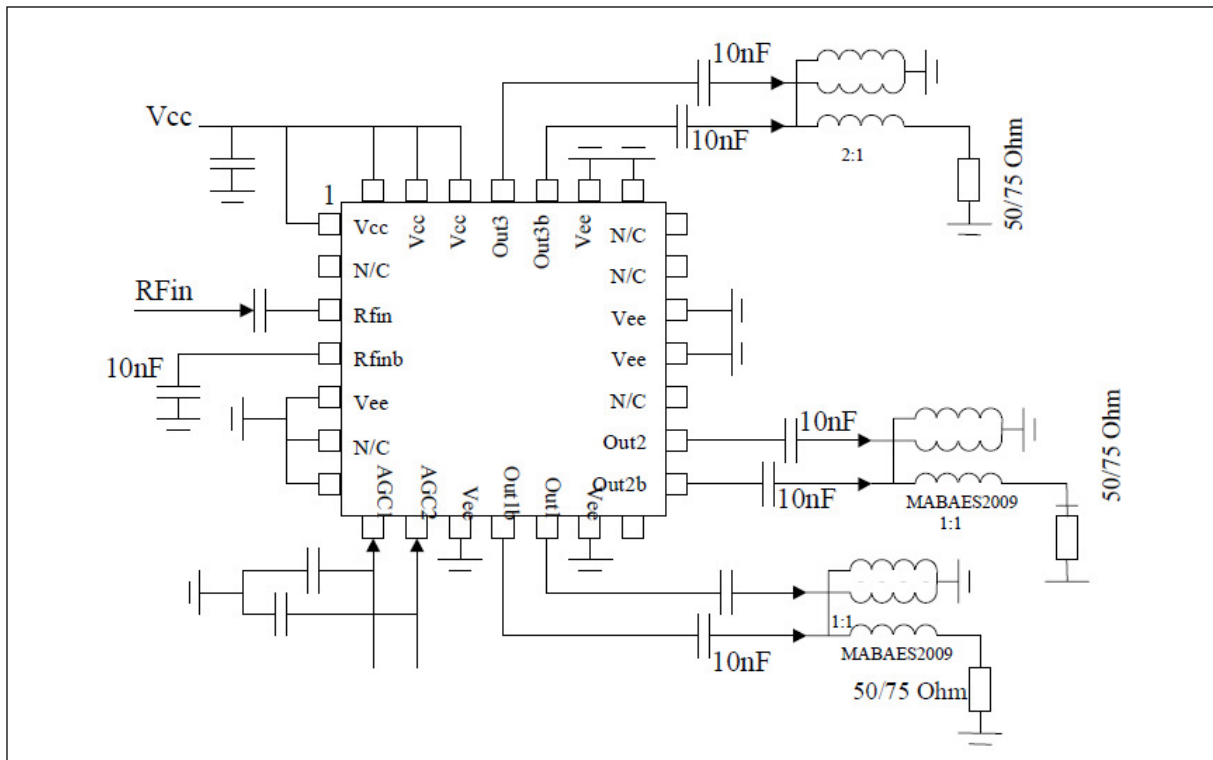


Figure 3 - Application Diagram - A (Differential)

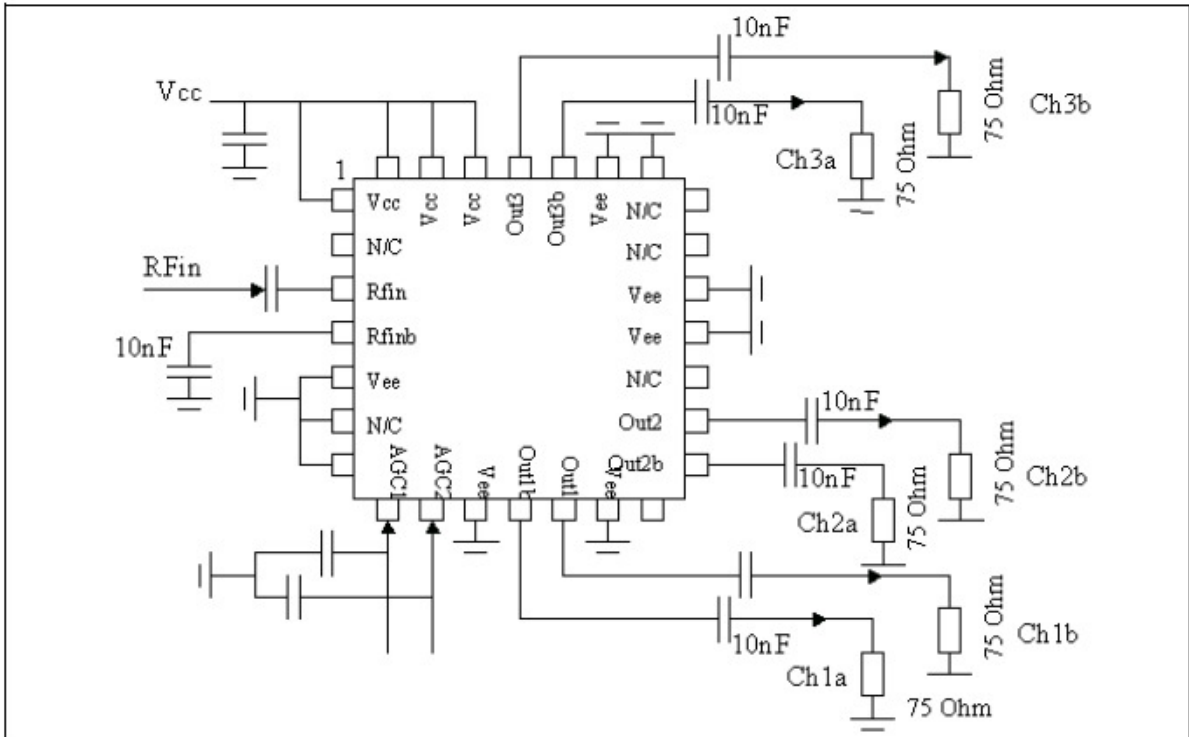


Figure 4 - Application Diagram B (Single Ended)

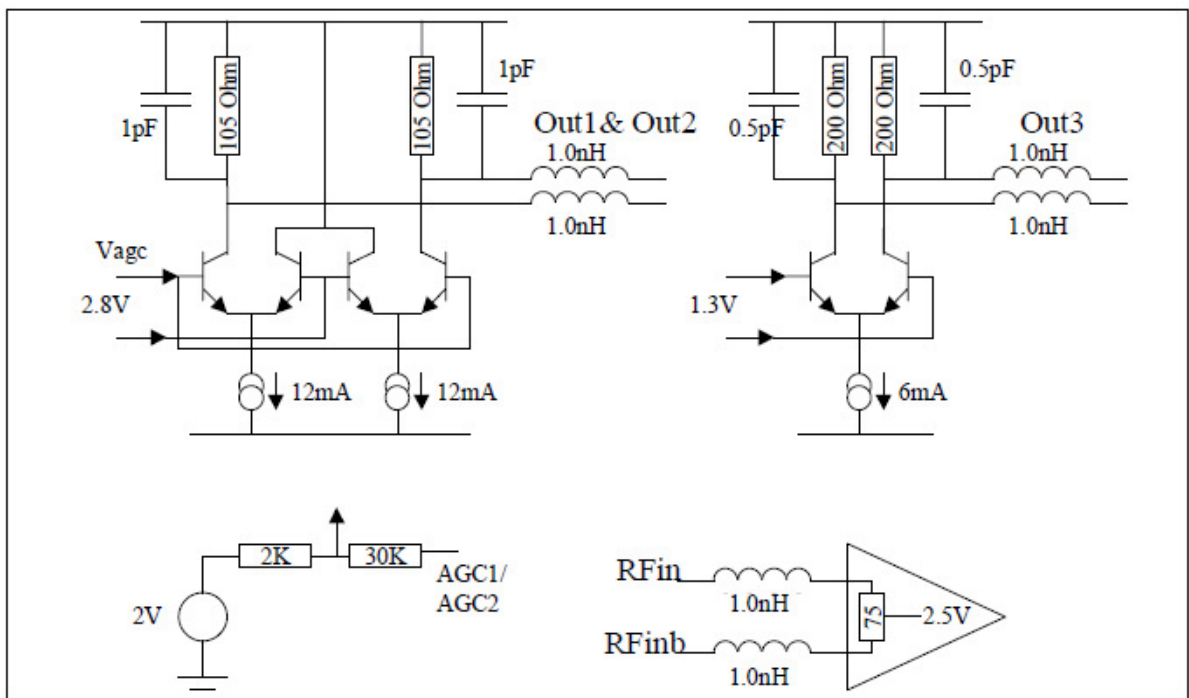


Figure 5 - PS12000 I/O Circuits

Absolute Maximum Ratings

Characteristic	Min	Max	Units	Comments
Supply Voltage (Vcc)	-0.5	6	V	
RFin		12	dBm	
All I/O ports	-0.5V	Vcc+0.5	V	
Storage Temperature	-55	150	°C	
Junction Temperature		125	°C	
ESD protection	2KV			Mil-std 883B / 3015 cat1

Operating Range

Characteristic	Min	Typ	Max	Units	Comments
Supply Voltage (Vcc)	4.75		5.25	V	
AGC1	0		5.25	V	
AGC2	0		5.25	V	
RFin Frequency Range	0.1		2000	MHz	
Operating Junction Temperature	-40		+120	°C	
Junc'n to Amb't resistance Theta Ja		50		°C/W	4 layer FR4 Board
Junc'n to Case resistance Theta Jc		20		°C/W	4 layer FR4 Board

DC Electrical Characteristics - Vcc=5V +/- 0.25V, Tamb = -40C to 80C, unless otherwise spec'd.

Characteristic	Min	Typ	Max	Units	Comments
Supply Current		100	130	mA	
Power Dissipation		500	683	mW	
RFin, RFinb DC Level		Vcc/2		V	
Out1, Out1b DC Level		Vcc-1.2		V	AGC1 = 0V
Out2, Out2b DC Level		Vcc-1.2		V	AGC2 = 0V
Out3, Out3b DC Level		Vcc-0.5		V	

AC Electrical Characteristics - $V_{cc}=5V \pm 0.25V$, $T_{amb} = -40C$ to $80C$, unless otherwise spec'd.

Characteristic	Min	Typ	Max	Units	Comments
Diff RFin impedance		75		Ohm	
S11		6		dB	(See Figure 36) (10MHz to 1000MHz)
Diff Out1 impedance		200		Ohm	
Diff Out2 impedance		200		Ohm	
Diff Out3 impedance		400		Ohm	
S21 Gain1 (Out1/RFin)	3.5	6.5	9.5	dB	100 Ohm Diff load, AGC1=0V (Max Gain)
S21 Gain2 (Out2/RFin)	3.5	6.5	9.5	dB	100 Ohm Diff load, AGC1=0V (Max Gain)
S21 Gain3 (Out3/RFin)	-3.5	-0.5	-2.5	dB	200 Ohm Diff load,
Gain Matching (Gain1 - Gain2)	-0.5	0	0.5	dB	AGC1 = AGC2 = 0V (Max Gain)
Gain Matching (Gain1- Gain2)	-0.5		0.5	dB	Gain1 = Gain2 = 5dB to 0dB, Figure 16 & Figure 18.
Gain Matching (Gain1 - Gain2)	-2		2	dB	Gain1 = Gain2 = 0dB to -25dB, Figure 17 & Figure 19 (Temp = 0C to 80C)
NF (Out1 & Out2)		7.5		dB	Figure 32 & Figure 33 (Gain = Max)
NF (Out1 & Out2)		12		dB	Figure 32 & Figure 33 (Gain = 0dB)
NF (Out1 & Out2)		15		dB	Figure 32 & Figure 33 (Gain = -5dB)
NF (Out1 & Out2)		18		dB	Figure 32 & Figure 33 (Gain = -10dB)
RFin P-dB compression	-2	0		dBm	
CMRR		40		dB	
AGC Range (Out1 & Out2)	40			dB	
AGC -3dB BW		45		MHz	
AGC Switching Time		15		ns	Max Gain to Min Gain (V _{agc} =0.8V to 4.2V)
AGC input referred Noise		200		nV/rt Hz	(Includes 26dB agc input resistor attenuator)
IIP3_100MHz		20		dBm	Figure 26 & Figure 27
IIP3_500MHz		17		dBm	Figure 26 & Figure 27
IIP3_1000MHz		13		dBm	Figure 26 & Figure 27
IIP3 variance / AGC	-1		1	dB	Gain = 5dB to -10dB, Figure 28 & Figure 29
IIP2_50MHz		55		dBm	Figure 20 & Figure 21 (0dB Gain)
IIP2_500MHz		42		dBm	Figure 20 & Figure 21 (0dB Gain)
Isolation (Output to Output)		50		dB	Balanced to Balanced
Isolation (output to output)		25			Single Ch1 to Single Ch2 Output
S21 (Output to Input)			-40	dB	Balanced to Balanced

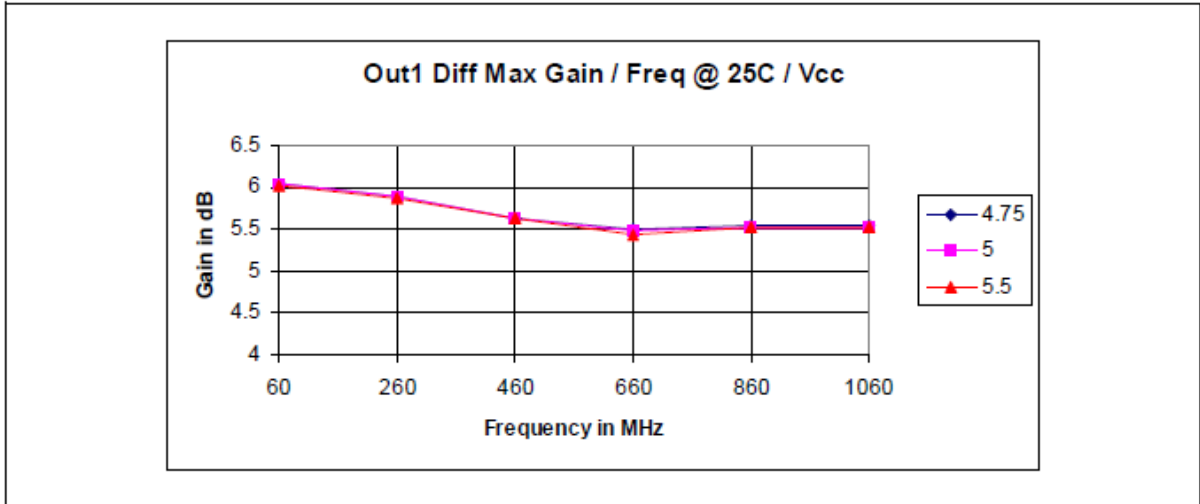


Figure 6 - Typical Ch1&2 Diff Gain / Freq / Vcc @ 25C

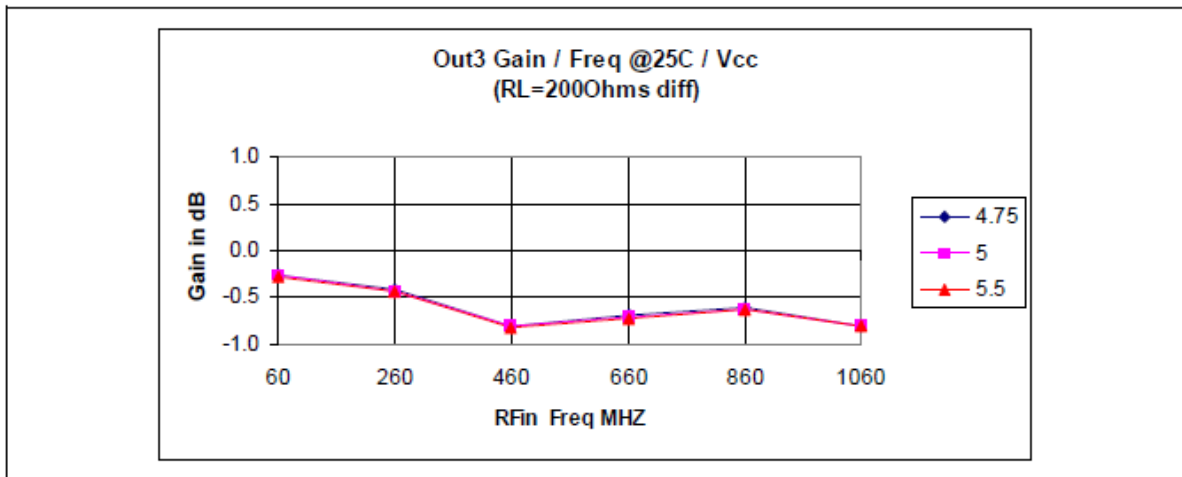


Figure 7 - Typical Ch3 Diff Gain / Freq / Vcc @ 25C

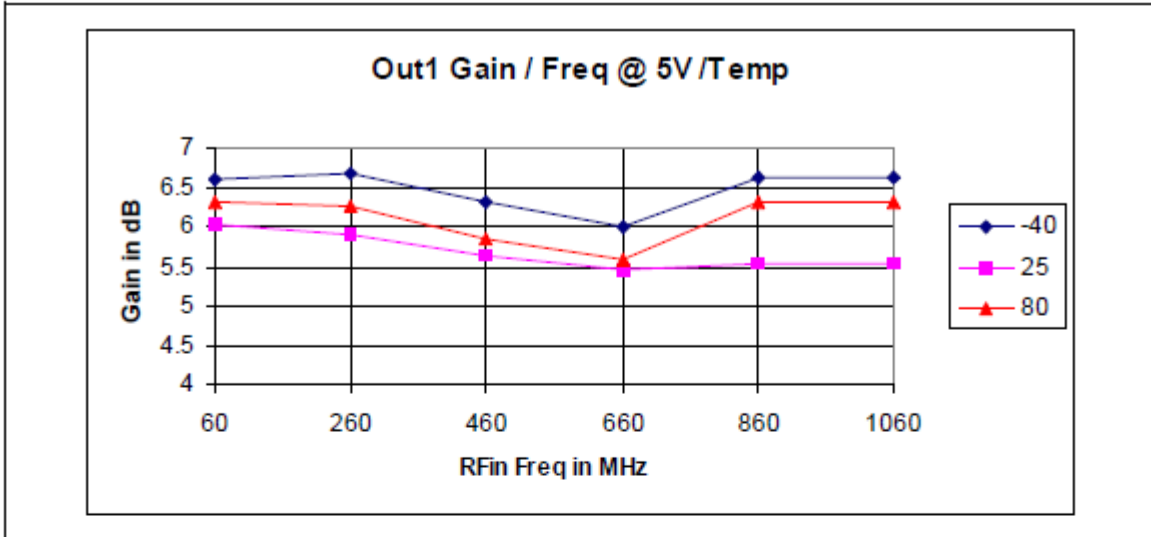


Figure 8 - Typical Ch1 & Ch2 Diff Max Gain / Freq / Temp @ 5V Vcc

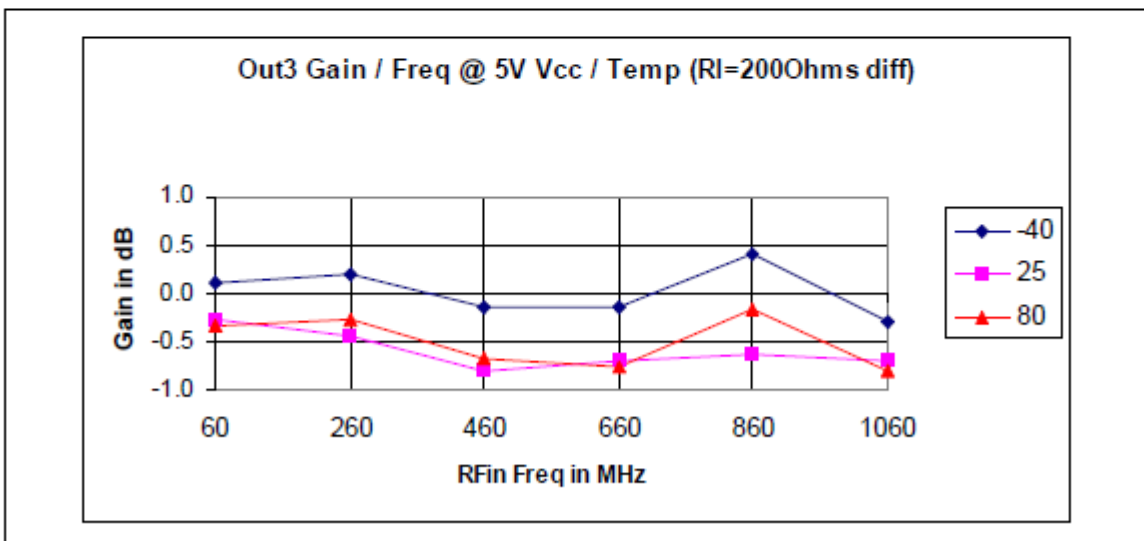


Figure 9 - Typical Ch3 Gain / Freq @ 5V / Temp (R1=200 Ohm)

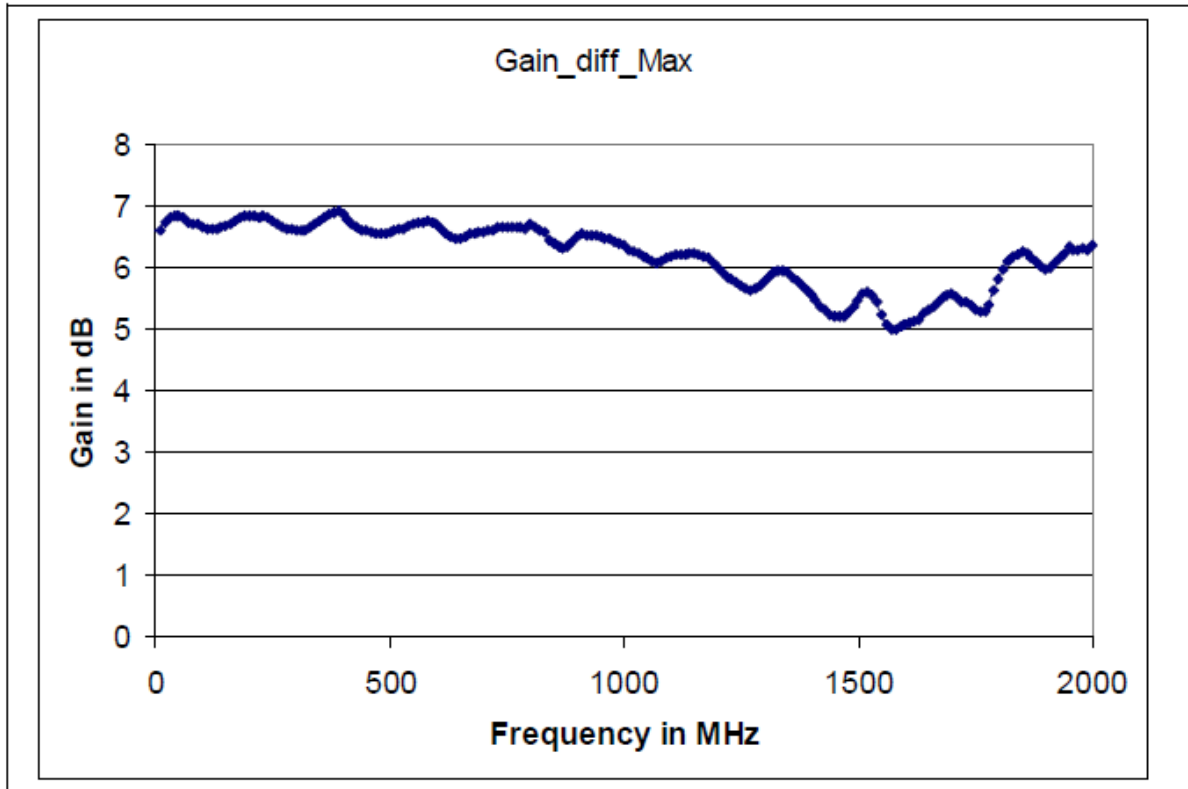


Figure 10 - Typical Diff Max Gain / Frequency

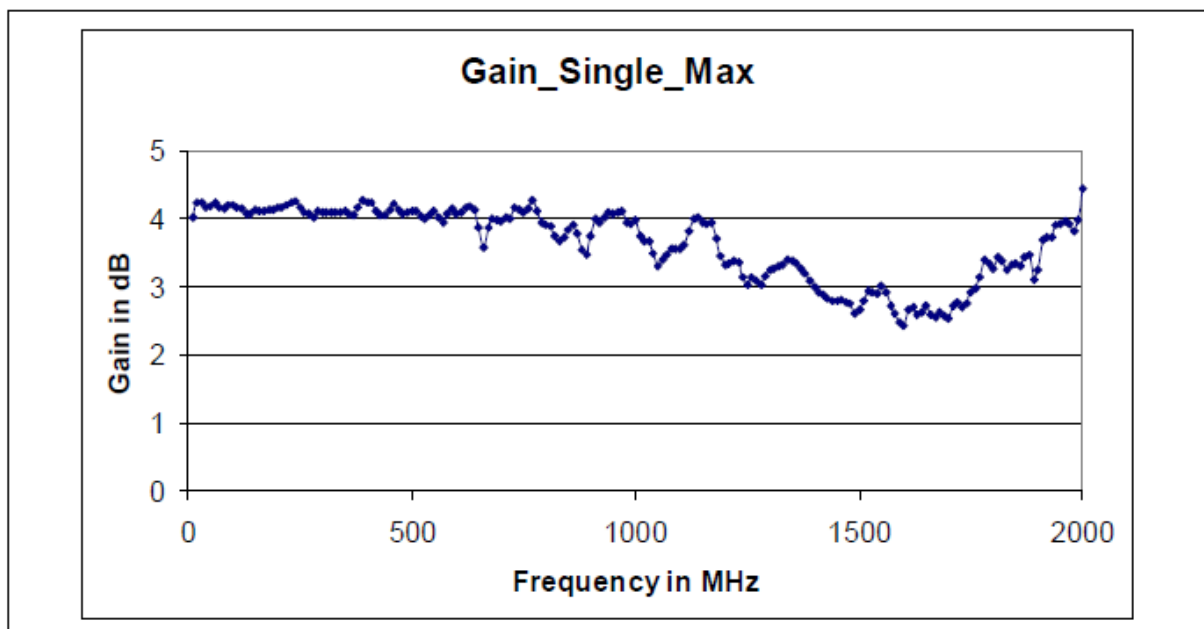


Figure 11 - Typical Single Ended Max Gain / Frequency

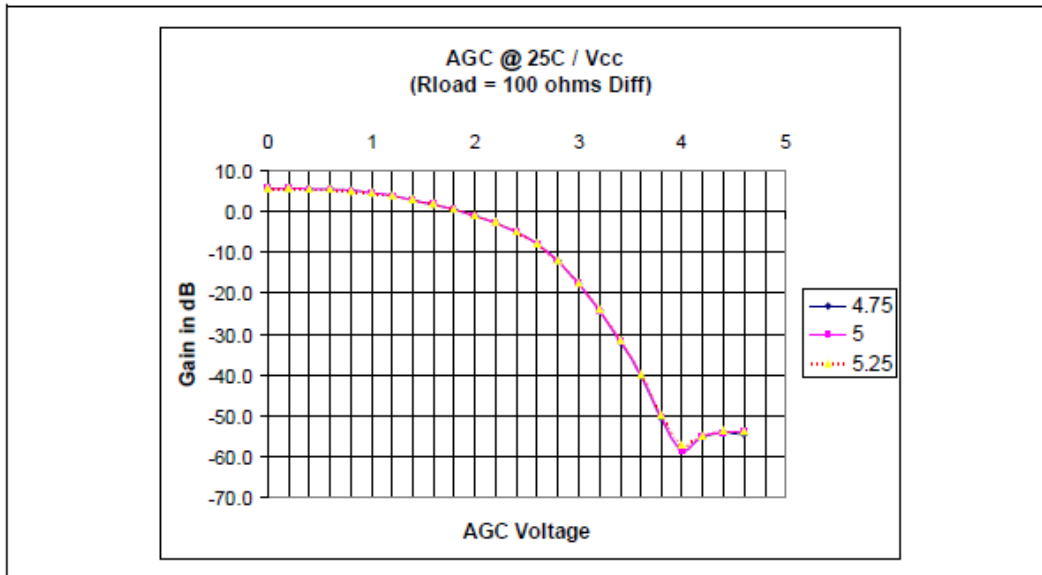


Figure 12 - Typical AGC / VCC @ 25C

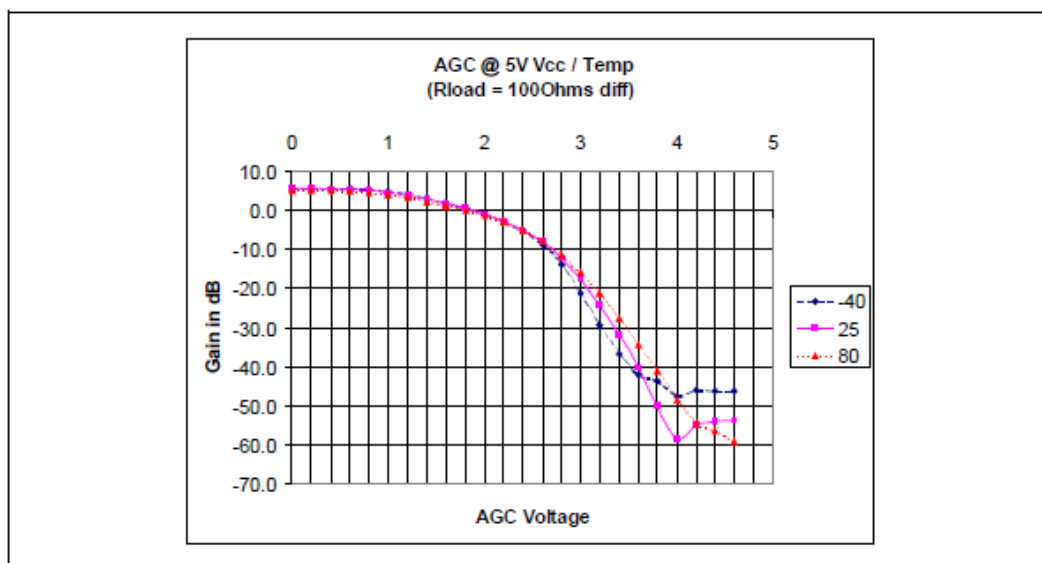


Figure 13 - Typical AGC / Temp @ 5 V Vcc

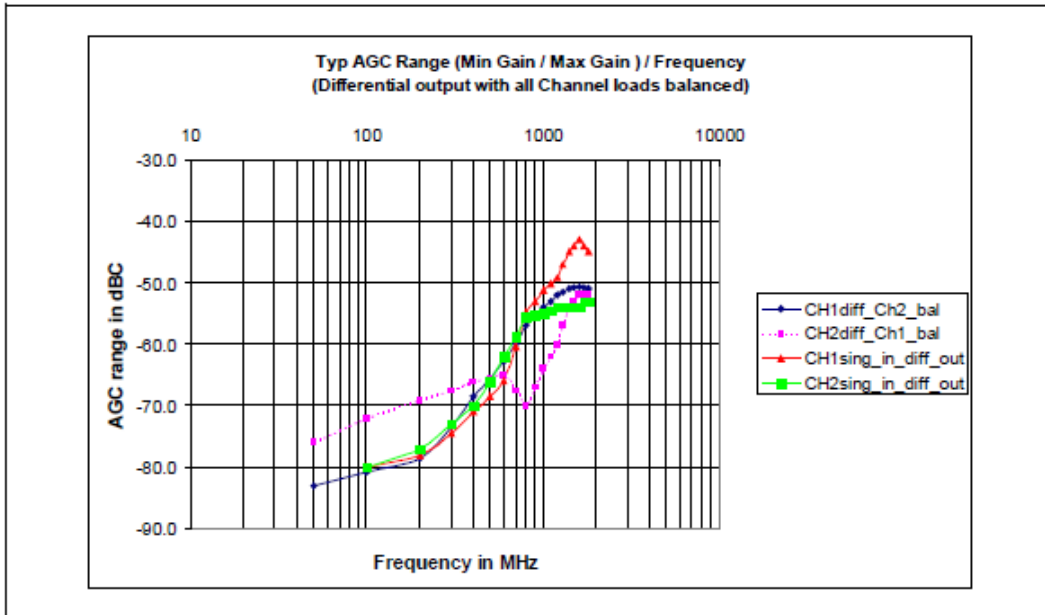


Figure 14 - Typical AGC Range / Frequency (Differential Output with all channel loads balanced)

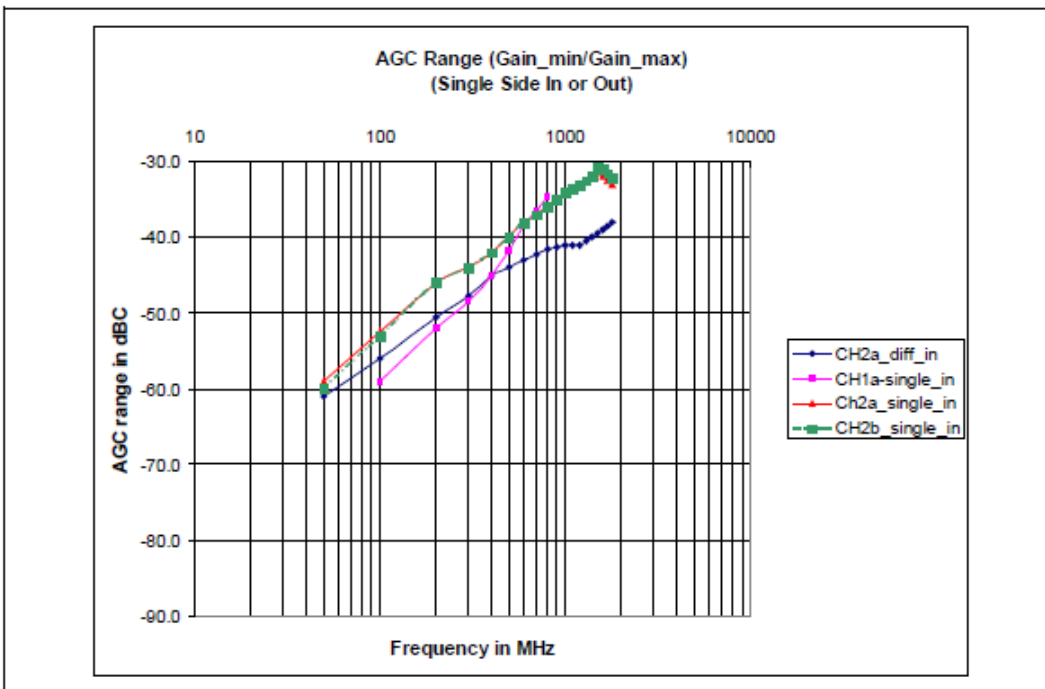


Figure 15 - Typical AGC Range / Frequency (Single Ended output)

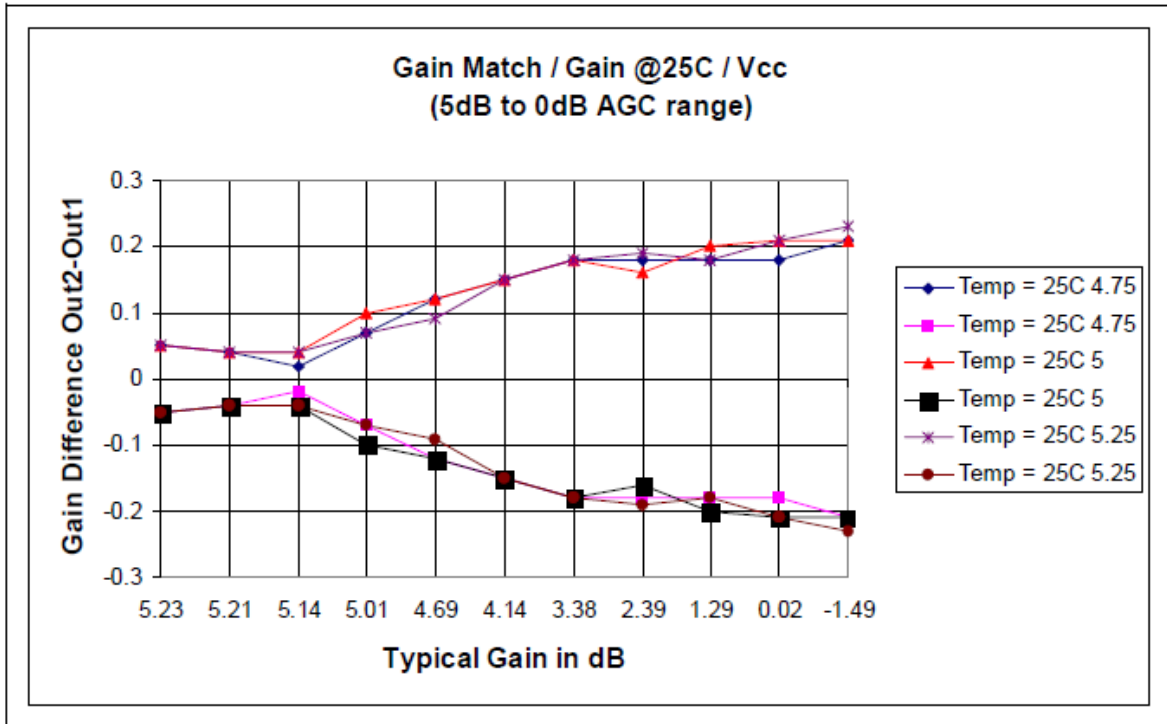


Figure 16 - Typical Gain Matching / AGC @25C / Vcc

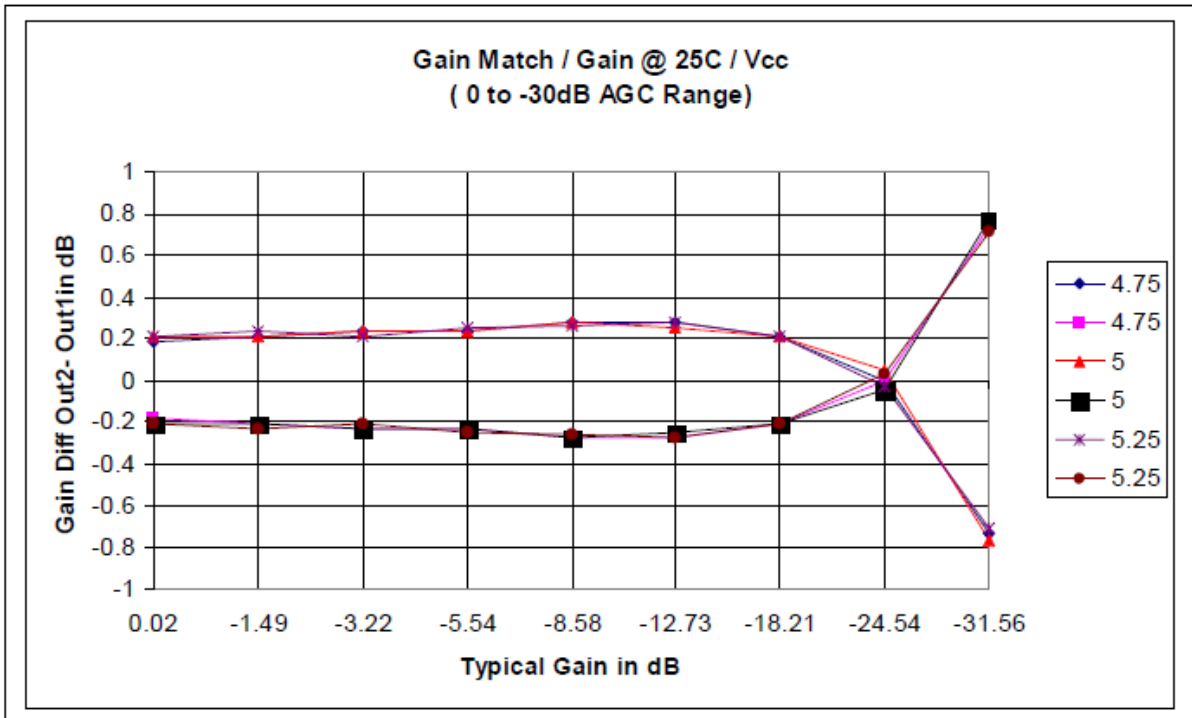


Figure 17 - Typical Gain Match 1 to 2 / Gain @ 25C / Vcc

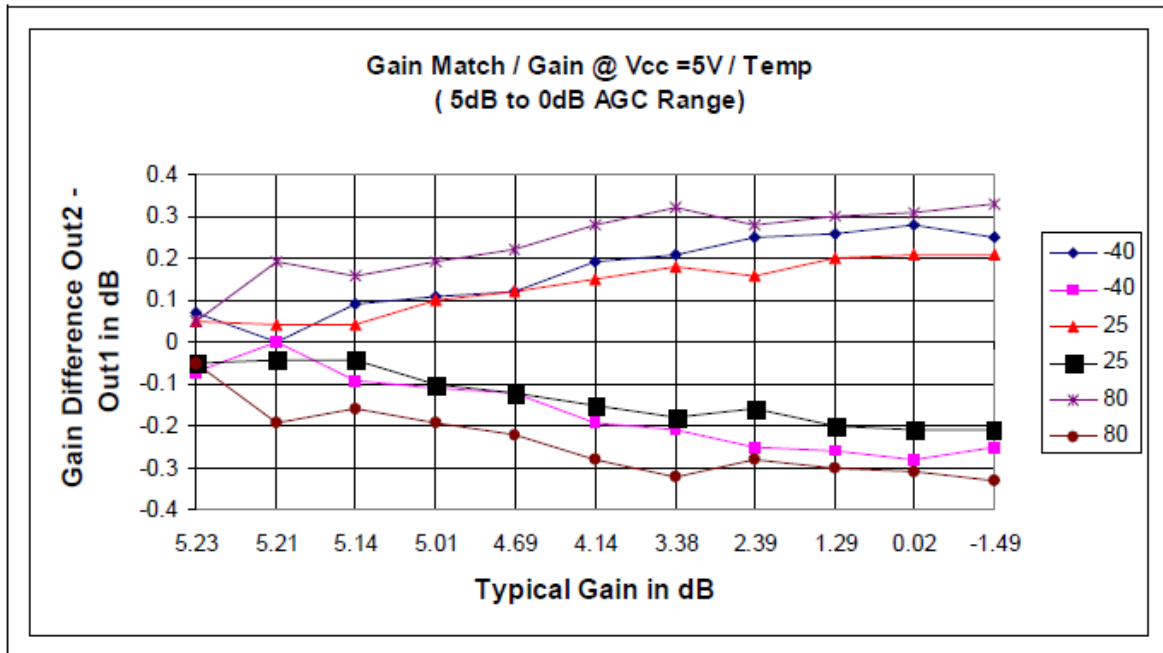


Figure 18 - Typical Gain Matching / AGC @ 5V Vcc / Temp

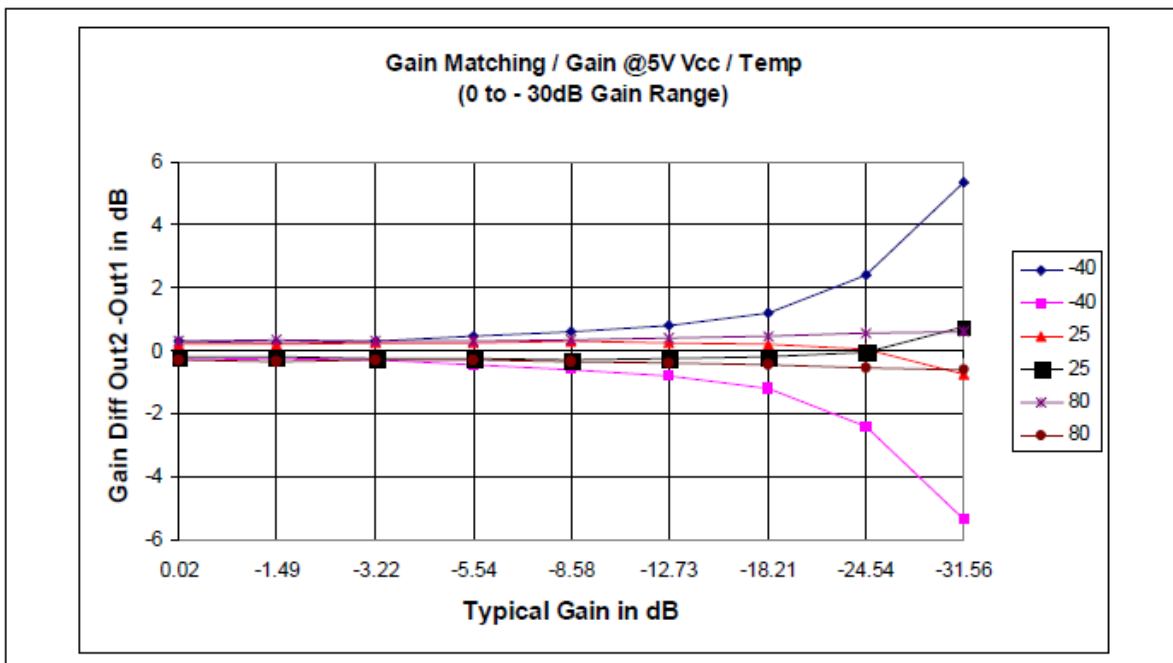


Figure 19 - Typical Gain Matching / AGC @ 5V Vcc / Temp

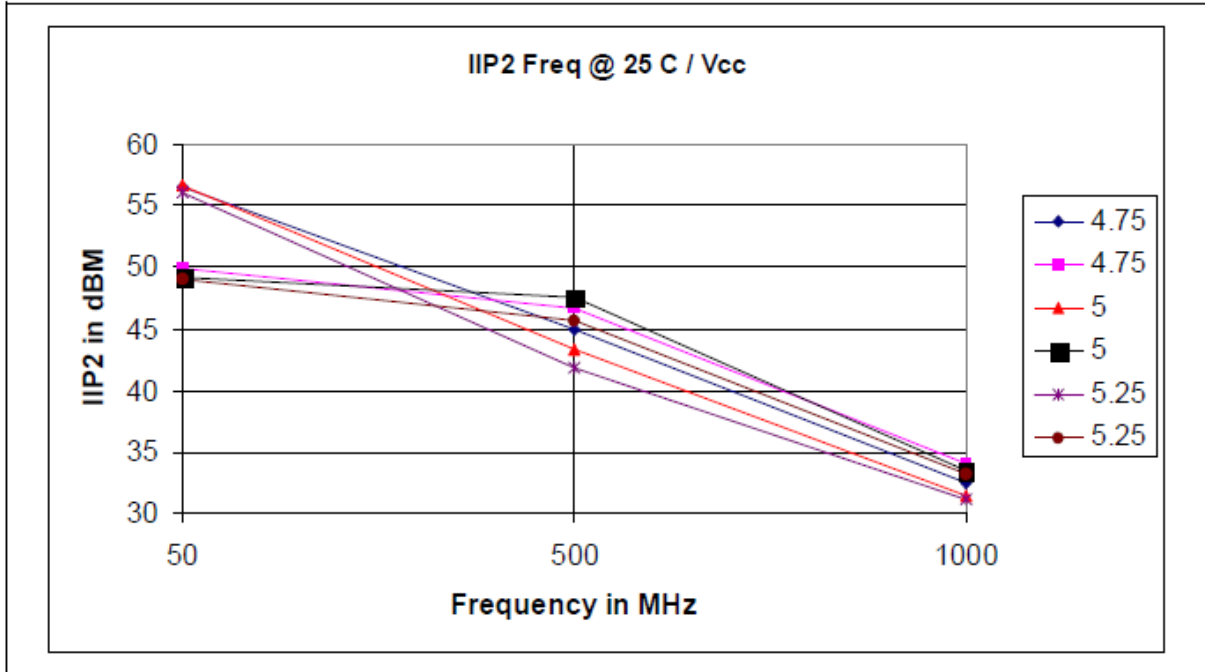


Figure 20 - Typical Out1 @ Out2 IIP2 / Frequency @ Max Gain @ 25C / Vcc

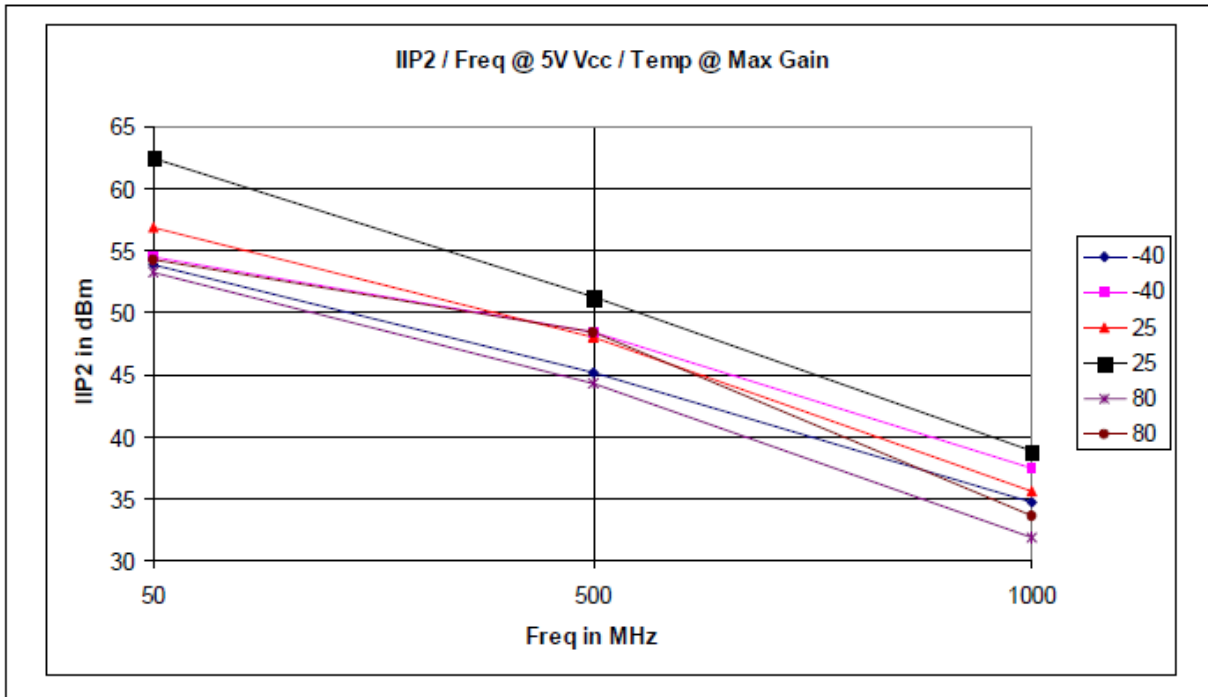


Figure 21 - Typical Out1 @ Out2 IIP2 / Frequency @ Max Gain @ 5V Vcc / Temp

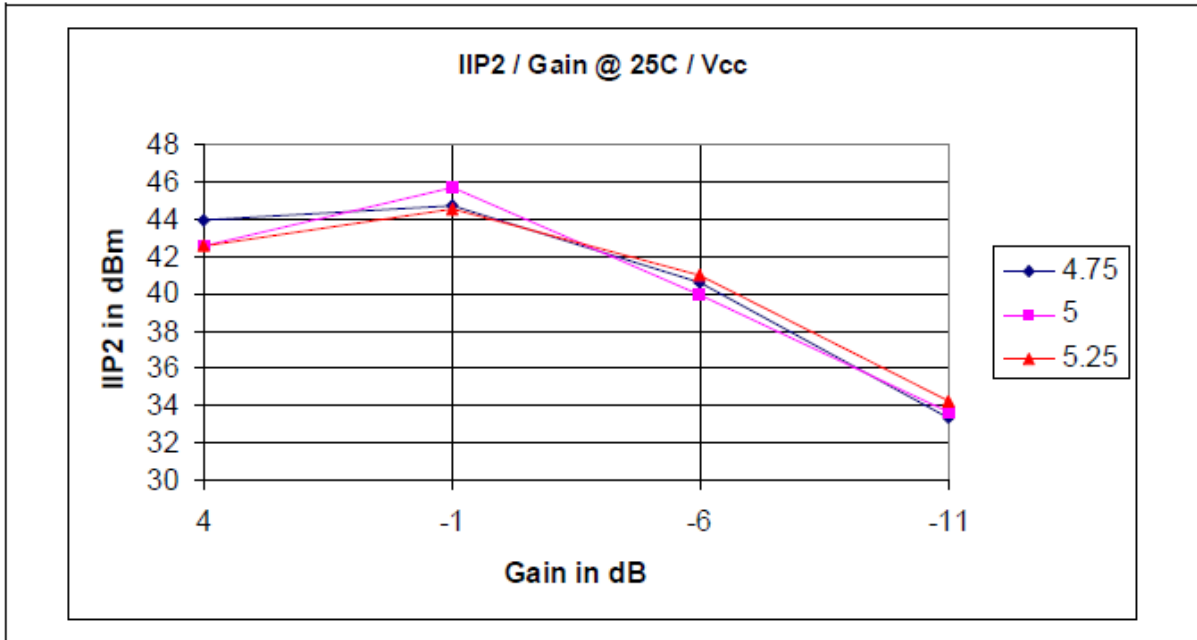


Figure 22 - Typical IIP2 / Gain @ 25C / Vcc @ 500MHz

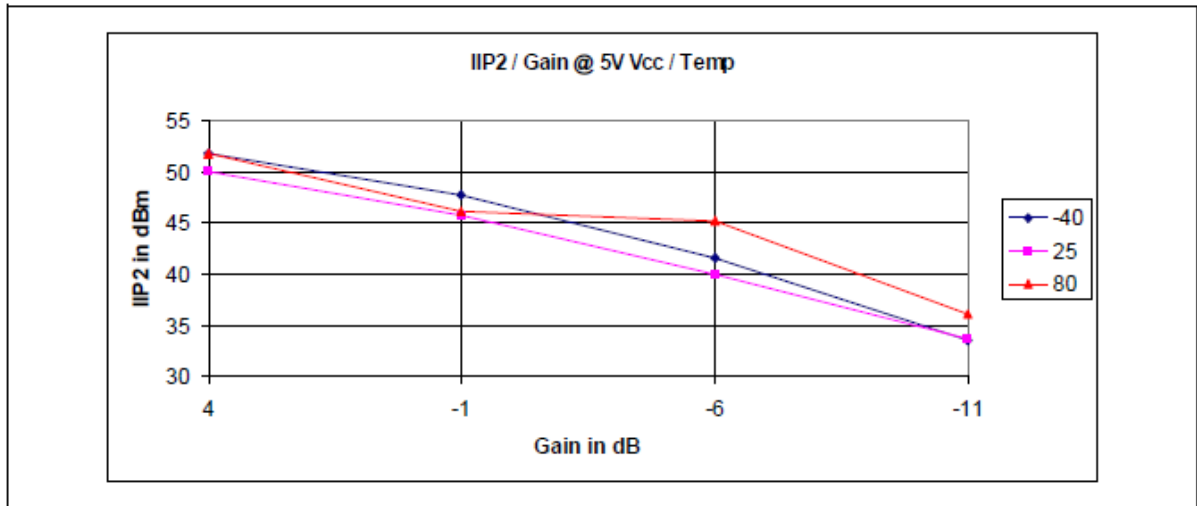


Figure 23 - Typical IIP2 / Gain @ 5V Vcc / Temp @ 500MHz

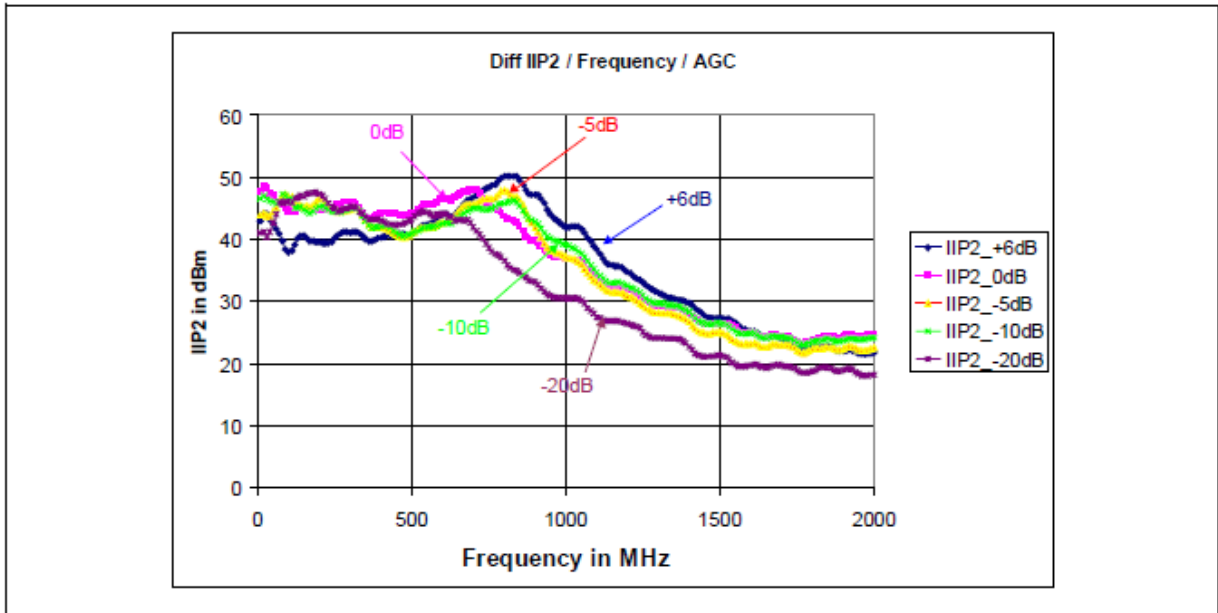


Figure 24 - Typical Differential IIP2 / Frequency / AGC Setting

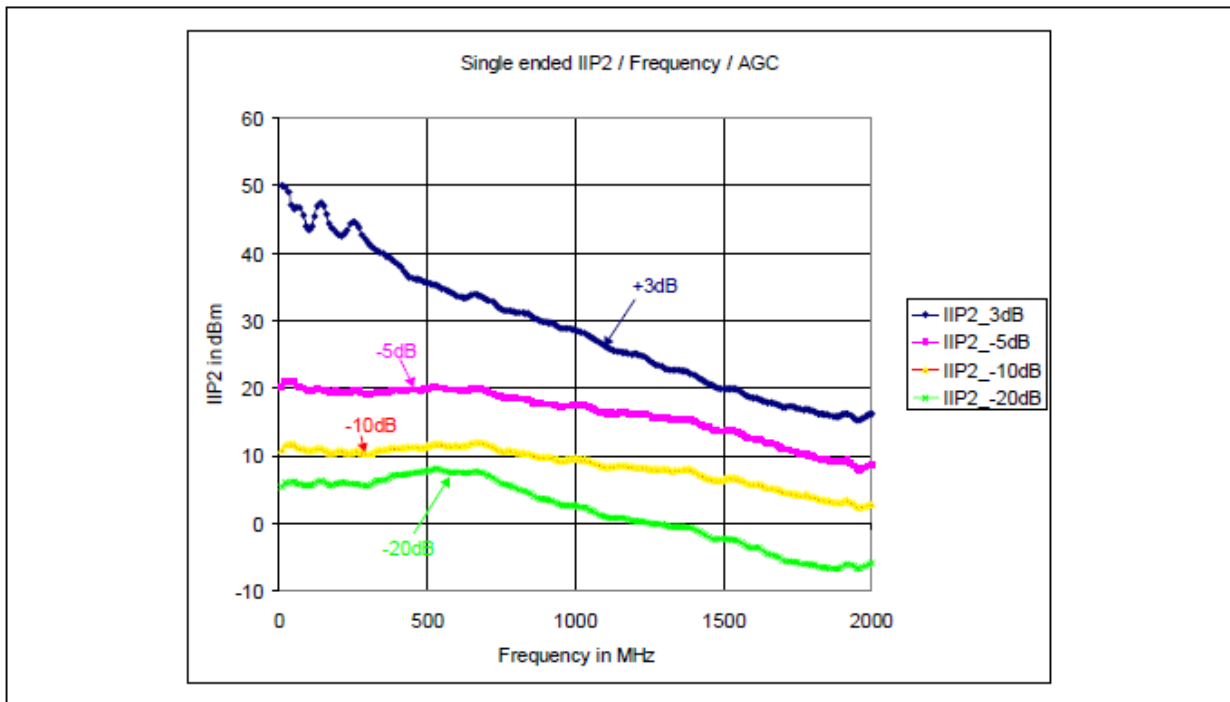


Figure 25 - Typical Single Ended IIP2 / Frequency / AGC

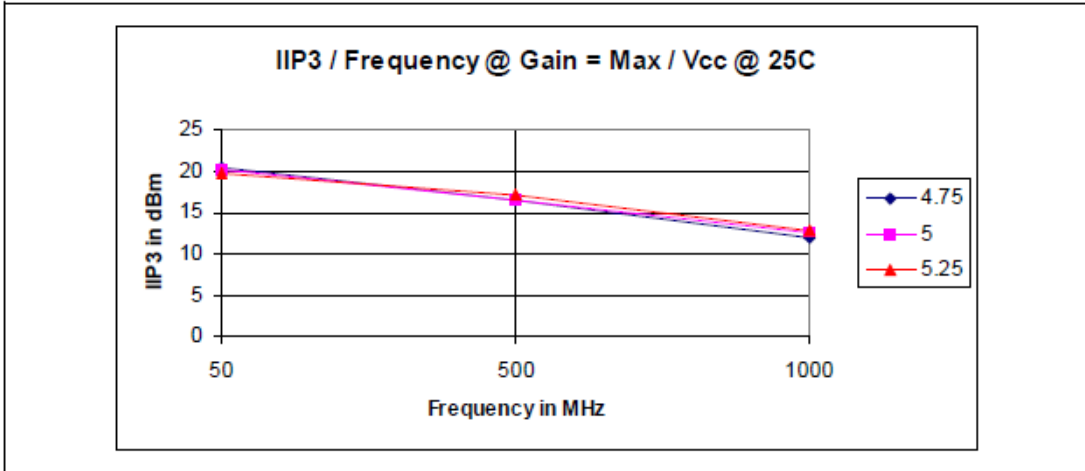


Figure 26 - Typical Out1, Out2 & Out3 IIP3 / Frequency @ Gain = Max / Vcc @ 25C

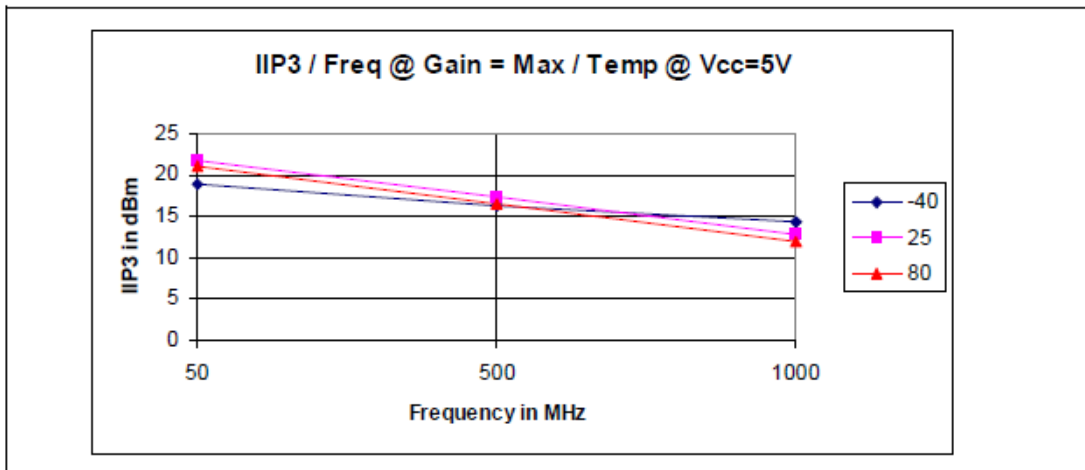


Figure 27 - Typical Out1, Out2 & Out3 IIP3 / Frequency @ Gain = Max / Temp @ 5V Vcc

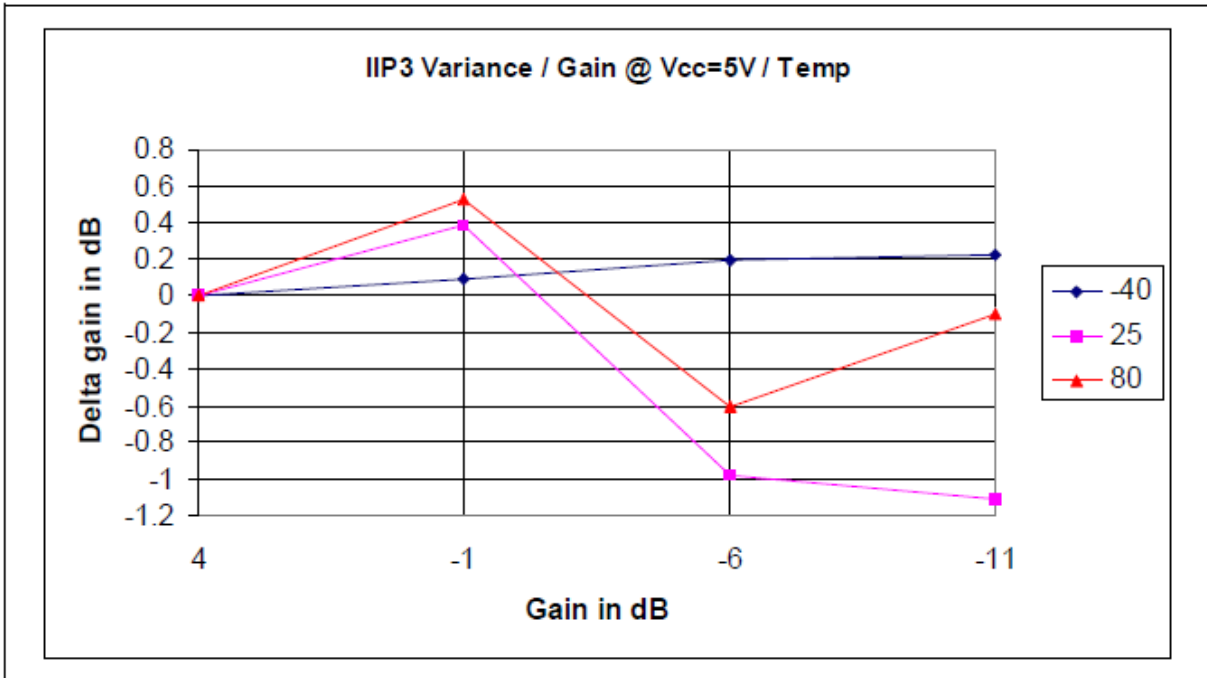


Figure 28 - Typical IIP3 Variance with AGC @ Vcc=5V /Temp @ 400MHz

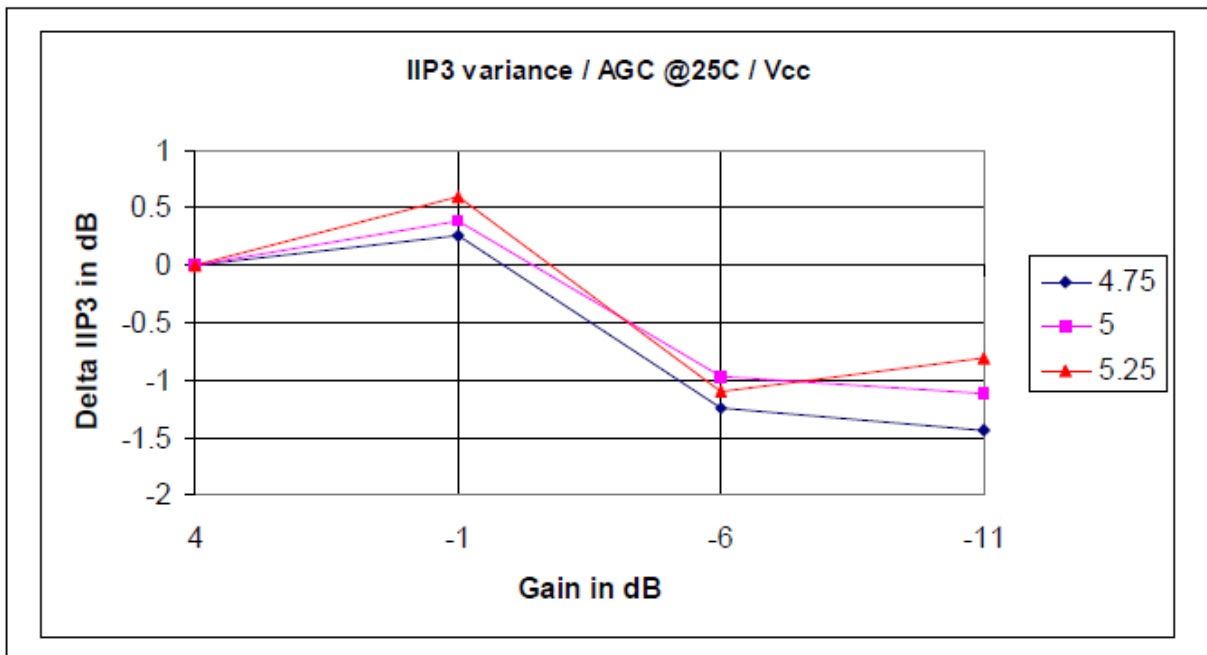


Figure 29 - Typical IIP3 variance with AGC @ 25C / Vcc @ 400MHz

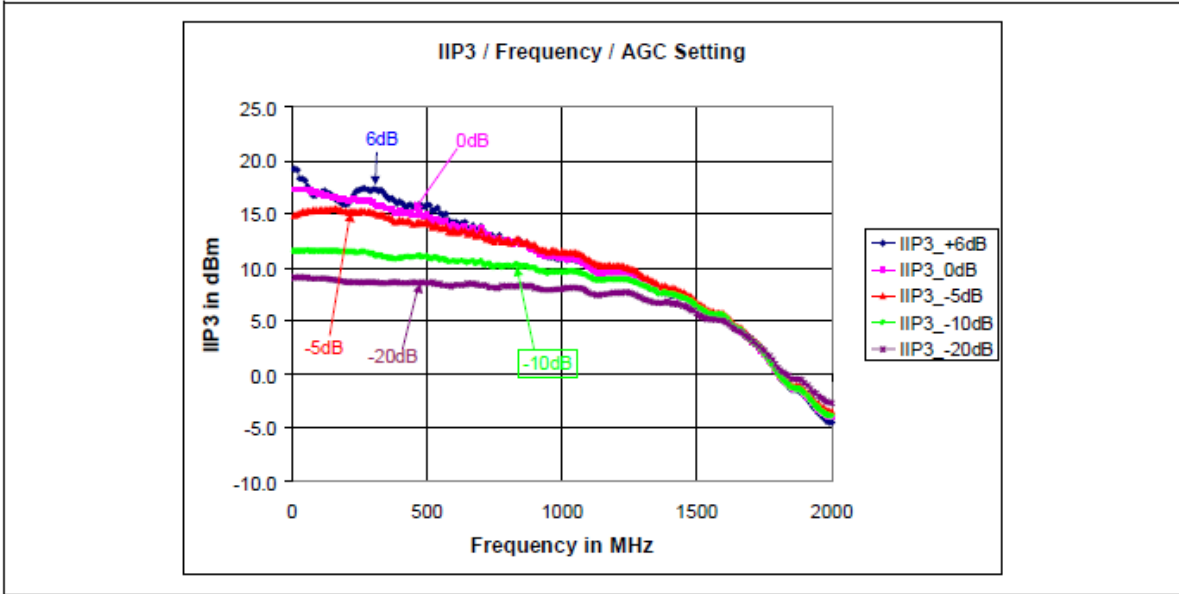


Figure 30 - Typical IIP3 @ Max Gain Differential / Frequency

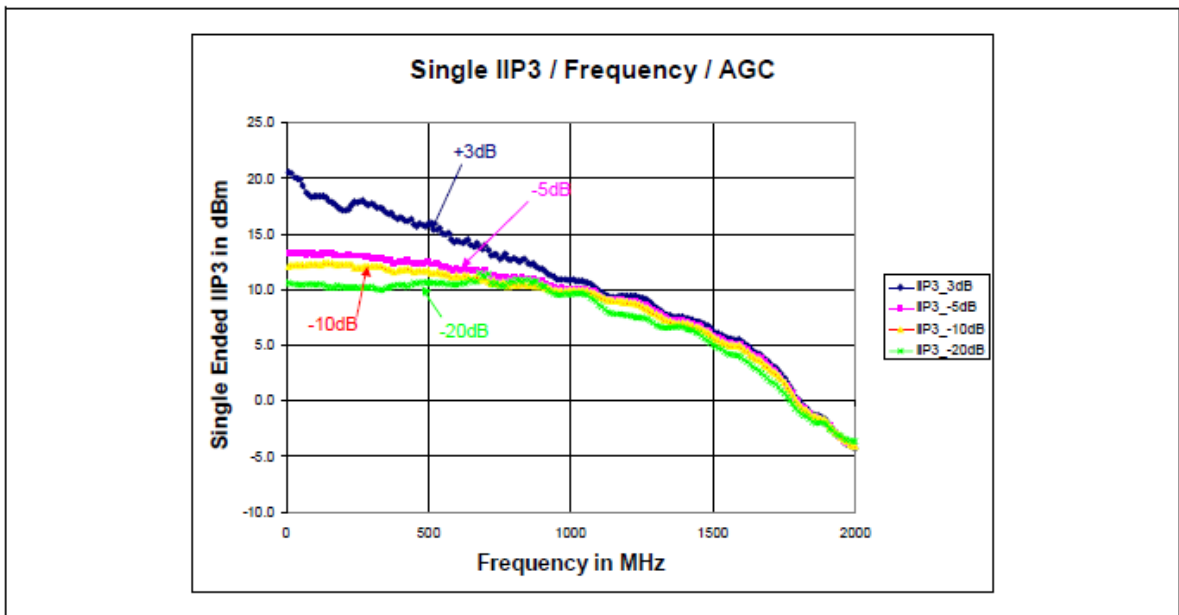


Figure 31 - Typical IIP3 Single Ended / Frequency / AGC

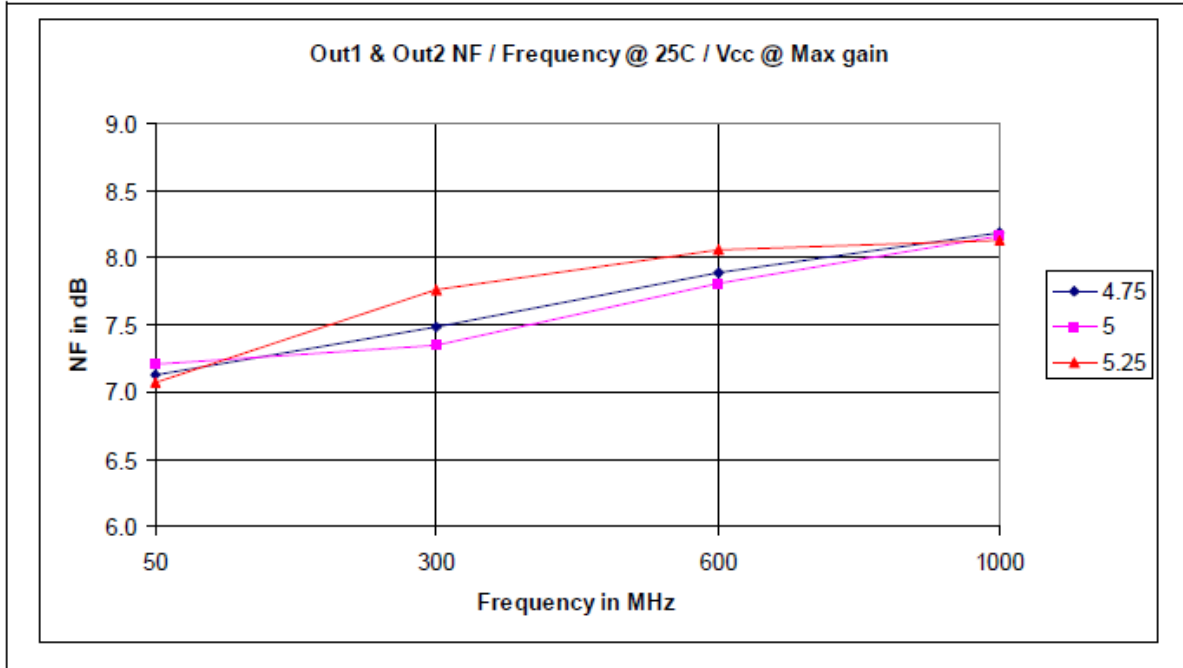


Figure 32 - Typical Differential NF / Frequency @ 25C / Vcc @ Max Gain

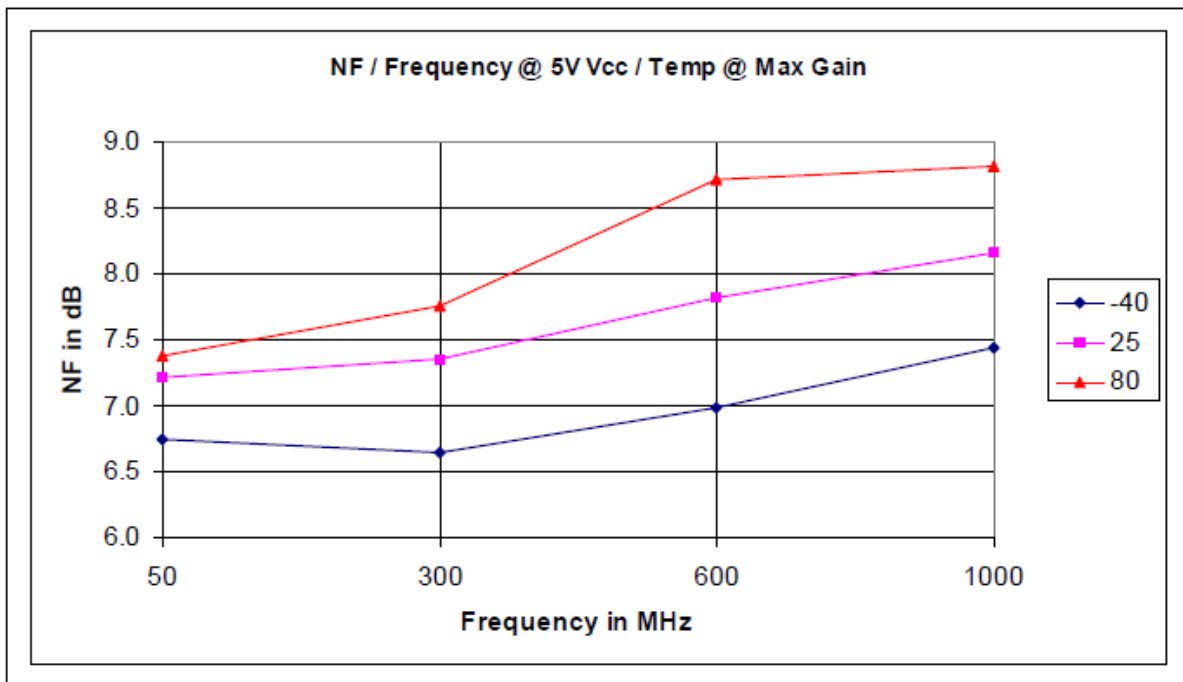


Figure 33 - Typical Differential NF / Frequency @ 5V Vcc / Temp @ Max Gain

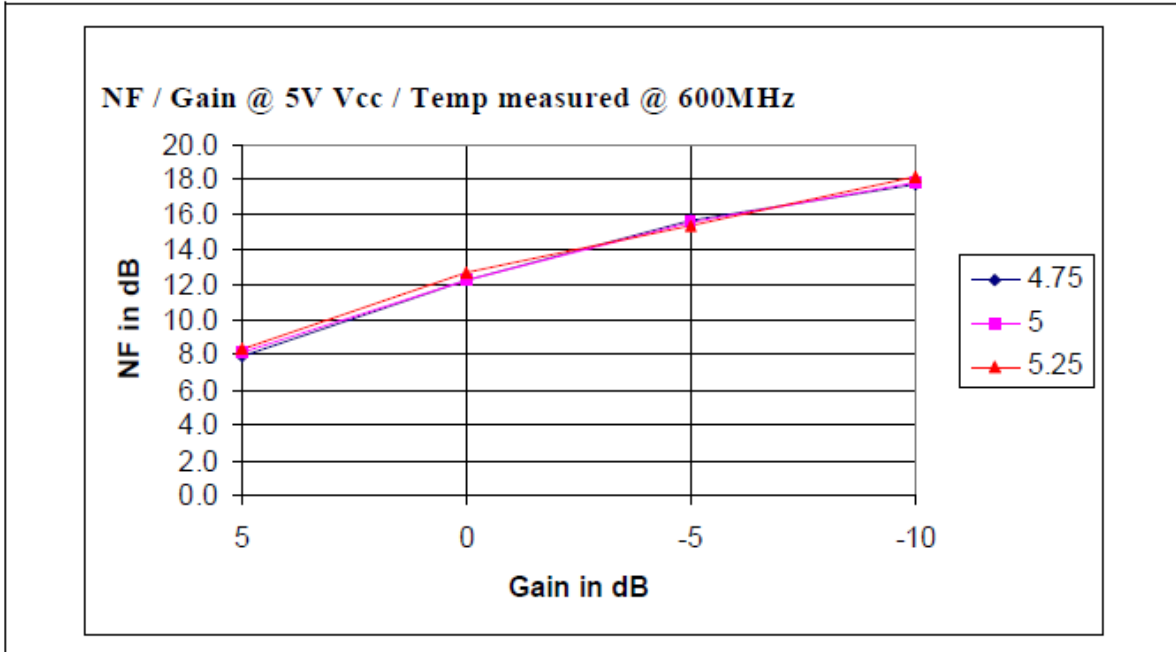


Figure 34 - Typical Differential NF / Gain @ 5V Vcc / Temp measured @ 600MHz

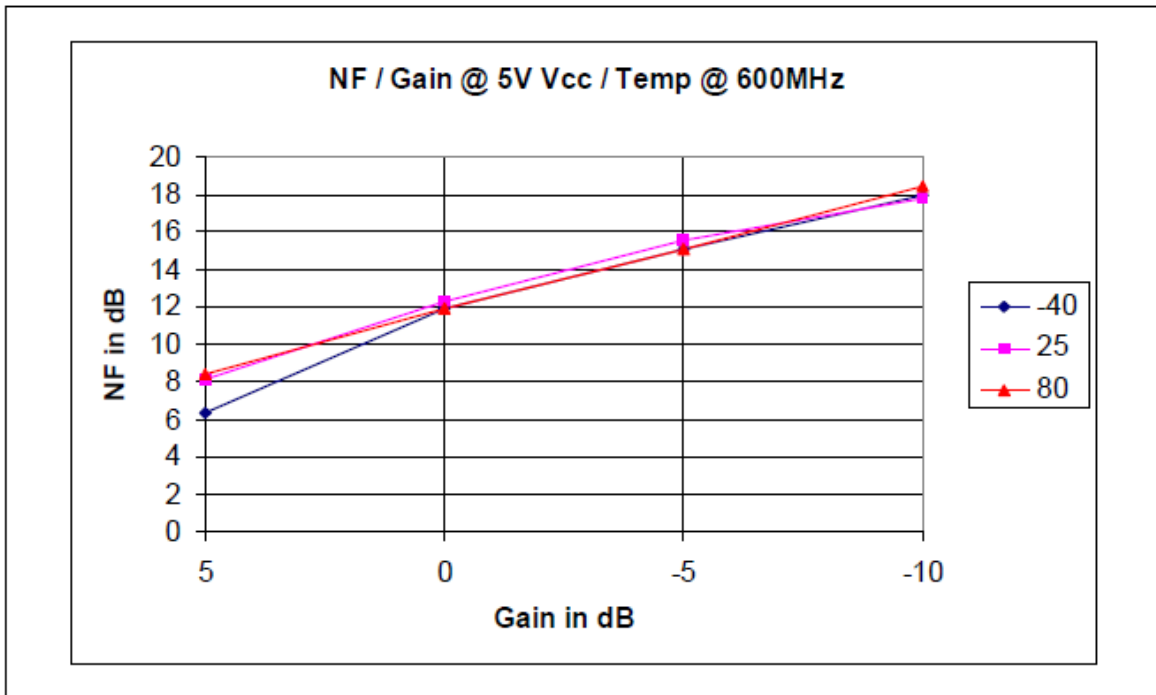


Figure 35 - Typical Differential NF / Gain @ 25C / Vcc measured @ 600MHz

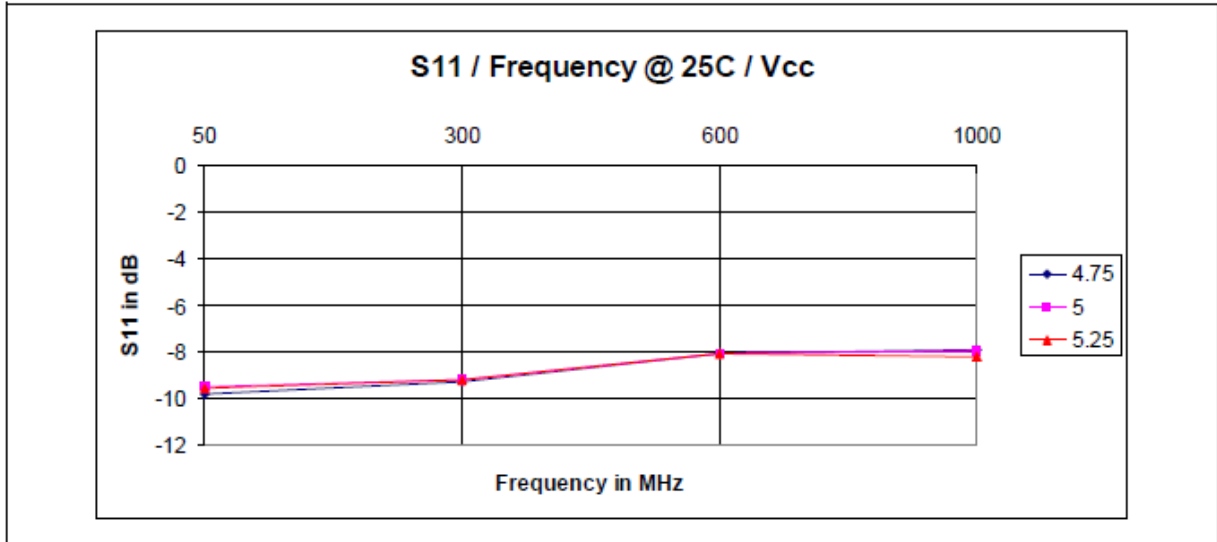


Figure 36 - Typical S11 in 50Ohm System

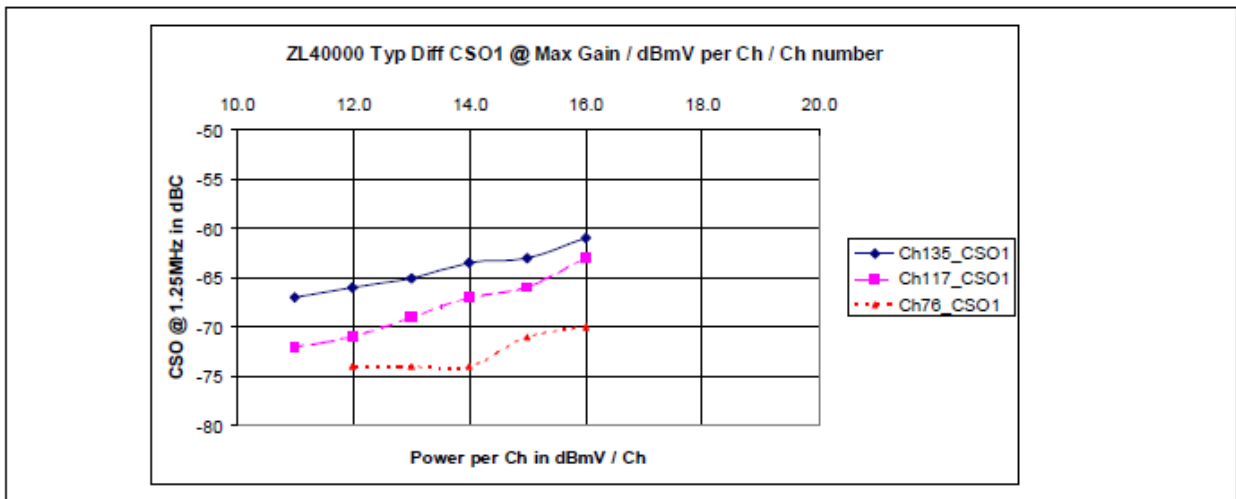


Figure 37 - Typical Differential CSO / Level per Channel @ Max Gain

CH136, CH117 and CH76 @ 850MHz, 745MHZ and 499MHz respectively) (Composite signal contains 130 Channels at 6MHz spacing between 50MHz and 850 MHz)

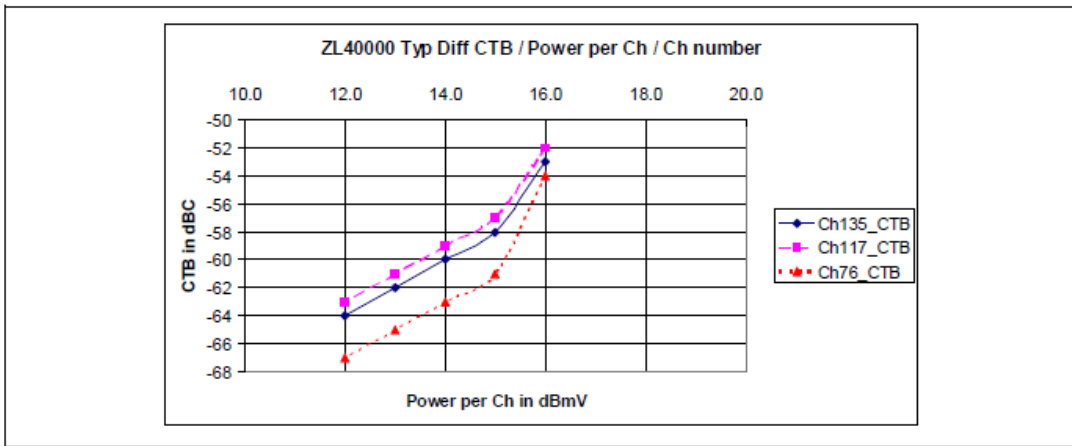


Figure 38 - Typical Differential CTB / Level per Channel @ Max Gain

(CH136, CH117 and CH76 @ 850MHz, 745MHz and 499MHz respectively) (Composite signal contains 130 Channels at 6MHz spacing between 50MHz and 850 MHz)

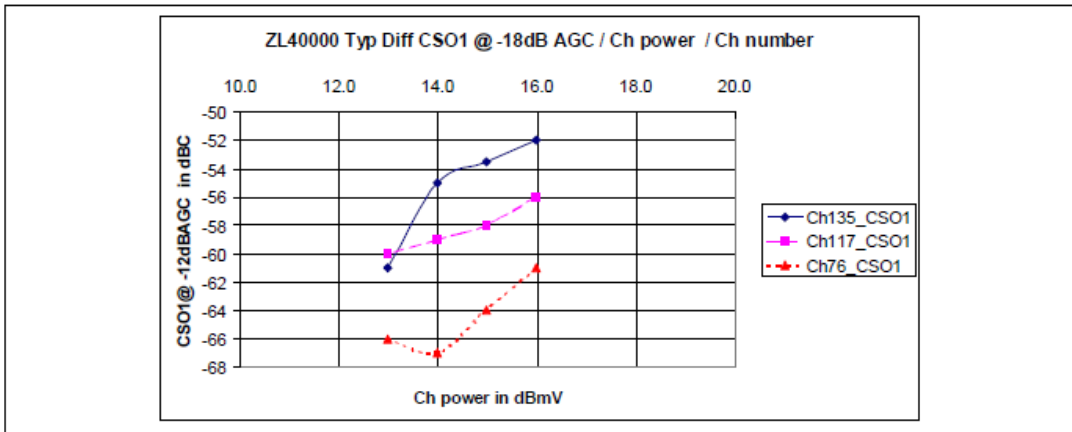


Figure 39 - Typical Differential CSO / Level per Channel @ -12dB Gain

(CH136, CH117 and CH76 @ 850MHz, 745MHz and 499MHz respectively) (Composite signal contains 130 Channels at 6MHz spacing between 50MHz and 850 MHz)

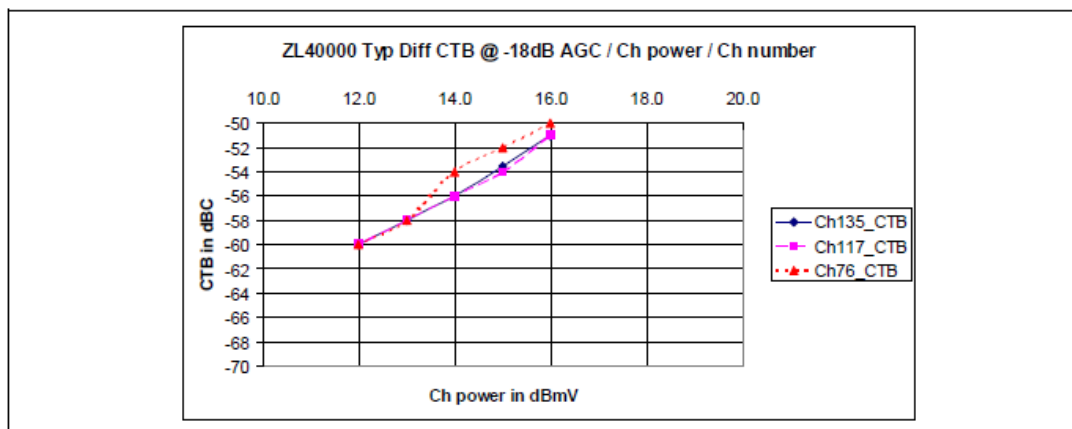


Figure 40 - CH136, CH117 and CH76 @ 850MHz, 745MHz and 499MHz respectively

(Composite signal contains 130 Channels at 6MHz spacing between 50MHz and 850 MHz)

Applications Notes

The PS12000 is a wide band RF signal conditioning and distribution circuit that can be used in many applications. The device has excellent signal handling performance and provides > 40 dB of AGC range over the full operating BW of DC to 2GHz.

The device's excellent dynamic performance and wide bandwidth make the it ideally suited to providing a separate buffered RF multi carrier signal to multiple tuner applications such as can be found in next generation Set Top Boxes, VCRs, DVDs and TVs for Digital Terrestrial, Cable and Satellite.

The device will also satisfy Analogue Terrestrial, Cable and Satellite requirements up to -35dBm / Ch in 130 Carrier Composite signals from 50MHz to 850 MHz with 6MHz channel spacing. The very high signal handling RF AGC stage makes the PS12000 suitable for use in all wide dynamic range receiver systems operating in the 1MHz to 2GHz band.

The PS12000 has excellent RF AGC performance providing > 40dB AGC range over the full DC to 2GHz operating range. The RF AGC range exceeds 60dBC from DC to 500MHz.

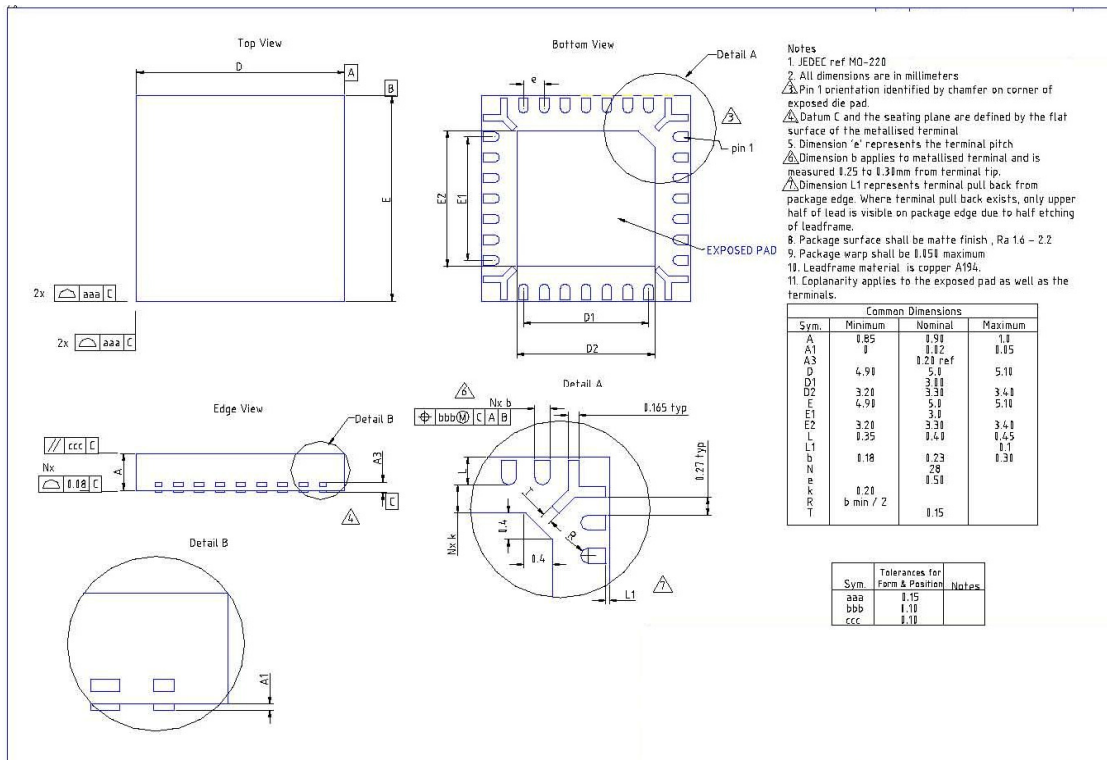
Both the excellent RF AGC range and the excellent Multi Carrier performance are achieved as a result of the balanced nature of the circuit. The PS12000 can be operated both single ended or differential at both the input and the output.

The performance achieved with the output signal used differential, increases the RF isolation and adds 20dB improvement above that achieved single ended. It also greatly reduces the second order distortion and inter modulation present at the output.

The best performance is achieved when all output ports are connected to balanced loads and if a particular channel is to be used single ended output, the unused output should be terminated with a matching load. The excellent RF range and high BW AGC control port makes the PS12000 suitable for applications in which fast level control or RF Signal Switching is required such as may be found in Instrumentation.

The RF AGC attenuator can be switched through 60dB of AGC range typically 15nS.

A pair of PS12000 with cross coupled outputs and a broad band quadrature phase shift unit can be used to build a broad band RF phase rotator that could be used in Agile Active Antenna Arrays for Transmitters with fast beam steering.



Package Outline for 28 lead MLP (5mm x 5mm)

For further information about this and other products, please visit: www.plesseysemiconductors.com

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Data Sheet 210913 issue 2

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